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"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "[Embedded - Microcontrollers](#)"

Details

| | |
|----------------------------|---|
| Product Status | Active |
| Core Processor | ARM® Cortex®-M0+ |
| Core Size | 32-Bit Single-Core |
| Speed | 32MHz |
| Connectivity | I ² C, IrDA, LINbus, SPI, UART/USART, USB |
| Peripherals | Brown-out Detect/Reset, DMA, I ² S, LCD, POR, PWM, WDT |
| Number of I/O | 40 |
| Program Memory Size | 192KB (192K x 8) |
| Program Memory Type | FLASH |
| EEPROM Size | 6K x 8 |
| RAM Size | 20K x 8 |
| Voltage - Supply (Vcc/Vdd) | 1.8V ~ 3.6V |
| Data Converters | A/D 13x12b; D/A 2x12b |
| Oscillator Type | Internal |
| Operating Temperature | -40°C ~ 85°C (TA) |
| Mounting Type | Surface Mount |
| Package / Case | 49-UFBGA, WLCSP |
| Supplier Device Package | 49-WLCSP (3.29x3.26) |
| Purchase URL | https://www.e-xfl.com/product-detail/stmicroelectronics/stm32l082czy6tr |

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3.10 Direct memory access (DMA)

The flexible 7-channel, general-purpose DMA is able to manage memory-to-memory, peripheral-to-memory and memory-to-peripheral transfers. The DMA controller supports circular buffer management, avoiding the generation of interrupts when the controller reaches the end of the buffer.

Each channel is connected to dedicated hardware DMA requests, with software trigger support for each channel. Configuration is done by software and transfer sizes between source and destination are independent.

The DMA can be used with the main peripherals: AES, SPI, I²C, USART, LPUART, general-purpose timers, DAC, and ADC.

3.11 Analog-to-digital converter (ADC)

A native 12-bit, extended to 16-bit through hardware oversampling, analog-to-digital converter is embedded into STM32L082xx device. It has up to 13 external channels and 3 internal channels (temperature sensor, voltage reference). Three channels, PA0, PA4 and PA5, are fast channels, while the others are standard channels.

The ADC performs conversions in single-shot or scan mode. In scan mode, automatic conversion is performed on a selected group of analog inputs.

The ADC frequency is independent from the CPU frequency, allowing maximum sampling rate of 1.14 MSPS even with a low CPU speed. The ADC consumption is low at all frequencies (~25 μ A at 10 kSPS, ~240 μ A at 1MSPS). An auto-shutdown function guarantees that the ADC is powered off except during the active conversion phase.

The ADC can be served by the DMA controller. It can operate from a supply voltage down to 1.65 V.

The ADC features a hardware oversampler up to 256 samples, this improves the resolution to 16 bits (see AN2668).

An analog watchdog feature allows very precise monitoring of the converted voltage of one, some or all scanned channels. An interrupt is generated when the converted voltage is outside the programmed thresholds.

The events generated by the general-purpose timers (TIMx) can be internally connected to the ADC start triggers, to allow the application to synchronize A/D conversions and timers.

3.12 Temperature sensor

The temperature sensor (T_{SENSE}) generates a voltage V_{SENSE} that varies linearly with temperature.

The temperature sensor is internally connected to the ADC_IN18 input channel which is used to convert the sensor output voltage into a digital value.

The sensor provides good linearity but it has to be calibrated to obtain good overall accuracy of the temperature measurement. As the offset of the temperature sensor varies from chip to chip due to process variation, the uncalibrated internal temperature sensor is suitable for applications that detect temperature changes only.

3.17 Timers and watchdogs

The ultra-low-power STM32L082xx devices include three general-purpose timers, one low-power timer (LPTIM), one basic timer, two watchdog timers and the SysTick timer.

[Table 9](#) compares the features of the general-purpose and basic timers.

Table 9. Timer feature comparison

| Timer | Counter resolution | Counter type | Prescaler factor | DMA request generation | Capture/compare channels | Complementary outputs |
|--------------|--------------------|-------------------|---------------------------------|------------------------|--------------------------|-----------------------|
| TIM2, TIM3 | 16-bit | Up, down, up/down | Any integer between 1 and 65536 | Yes | 4 | No |
| TIM21, TIM22 | 16-bit | Up, down, up/down | Any integer between 1 and 65536 | No | 2 | No |
| TIM6, TIM7 | 16-bit | Up | Any integer between 1 and 65536 | Yes | 0 | No |

3.17.1 General-purpose timers (TIM2, TIM3, TIM21 and TIM22)

There are four synchronizable general-purpose timers embedded in the STM32L082xx device (see [Table 9](#) for differences).

TIM2, TIM3

TIM2 and TIM3 are based on 16-bit auto-reload up/down counter. It includes a 16-bit prescaler. It features four independent channels each for input capture/output compare, PWM or one-pulse mode output.

The TIM2/TIM3 general-purpose timers can work together or with the TIM21 and TIM22 general-purpose timers via the Timer Link feature for synchronization or event chaining. Their counter can be frozen in debug mode. Any of the general-purpose timers can be used to generate PWM outputs.

TIM2/TIM3 have independent DMA request generation.

These timers are capable of handling quadrature (incremental) encoder signals and the digital outputs from 1 to 3 hall-effect sensors.

TIM21 and TIM22

TIM21 and TIM22 are based on a 16-bit auto-reload up/down counter. They include a 16-bit prescaler. They have two independent channels for input capture/output compare, PWM or one-pulse mode output. They can work together and be synchronized with the TIM2/TIM3, full-featured general-purpose timers.

They can also be used as simple time bases and be clocked by the LSE clock source (32.768 kHz) to provide time bases independent from the main CPU clock.

3.18 Communication interfaces

3.18.1 I²C bus

Up to three I²C interfaces (I2C1, I2C2 and I2C3) can operate in multimaster or slave modes.

Each I²C interface can support Standard mode (Sm, up to 100 kbit/s), Fast mode (Fm, up to 400 kbit/s) and Fast Mode Plus (Fm+, up to 1 Mbit/s) with 20 mA output drive on some I/Os.

7-bit and 10-bit addressing modes, multiple 7-bit slave addresses (2 addresses, 1 with configurable mask) are also supported as well as programmable analog and digital noise filters.

Table 10. Comparison of I2C analog and digital filters

| | Analog filter | Digital filter |
|----------------------------------|---|--|
| Pulse width of suppressed spikes | ≥ 50 ns | Programmable length from 1 to 15 I2C peripheral clocks |
| Benefits | Available in Stop mode | 1. Extra filtering capability vs. standard requirements. 2. Stable length |
| Drawbacks | Variations depending on temperature, voltage, process | Wakeup from Stop on address match is not available when digital filter is enabled. |

In addition, I2C1 and I2C3 provide hardware support for SMBus 2.0 and PMBus 1.1: ARP capability, Host notify protocol, hardware CRC (PEC) generation/verification, timeouts verifications and ALERT protocol management. I2C1/I2C3 also have a clock domain independent from the CPU clock, allowing the I2C1/I2C3 to wake up the MCU from Stop mode on address match.

Each I2C interface can be served by the DMA controller.

Refer to [Table 11](#) for an overview of I2C interface features.

Table 11. STM32L082xx I²C implementation

| I2C features ⁽¹⁾ | I2C1 | I2C2 | I2C3 |
|--|------|------------------|------|
| 7-bit addressing mode | X | X | X |
| 10-bit addressing mode | X | X | X |
| Standard mode (up to 100 kbit/s) | X | X | X |
| Fast mode (up to 400 kbit/s) | X | X | X |
| Fast Mode Plus with 20 mA output drive I/Os (up to 1 Mbit/s) | X | X ⁽²⁾ | X |
| Independent clock | X | - | X |
| SMBus | X | - | X |
| Wakeup from STOP | X | - | X |

1. X = supported.

2. See [Table 15: STM32L072xxx pin definition on page 39](#) for the list of I/Os that feature Fast Mode Plus capability

3.18.2 Universal synchronous/asynchronous receiver transmitter (USART)

The four USART interfaces (USART1, USART2, USART4 and USART5) are able to communicate at speeds of up to 4 Mbit/s.

They provide hardware management of the CTS, RTS and RS485 driver enable (DE) signals, multiprocessor communication mode, master synchronous communication and single-wire half-duplex communication mode. USART1 and USART2 also support SmartCard communication (ISO 7816), IrDA SIR ENDEC, LIN Master/Slave capability, auto baud rate feature and has a clock domain independent from the CPU clock, allowing to wake up the MCU from Stop mode using baudrates up to 42 Kbaud.

All USART interfaces can be served by the DMA controller.

[Table 12](#) for the supported modes and features of USART interfaces.

Table 12. USART implementation

| USART modes/features ⁽¹⁾ | USART1 and USART2 | USART4 and USART5 |
|---|-------------------|-------------------|
| Hardware flow control for modem | X | X |
| Continuous communication using DMA | X | X |
| Multiprocessor communication | X | X |
| Synchronous mode ⁽²⁾ | X | X |
| Smartcard mode | X | - |
| Single-wire half-duplex communication | X | X |
| IrDA SIR ENDEC block | X | - |
| LIN mode | X | - |
| Dual clock domain and wakeup from Stop mode | X | - |
| Receiver timeout interrupt | X | - |
| Modbus communication | X | - |
| Auto baud rate detection (4 modes) | X | - |
| Driver Enable | X | X |

1. X = supported.

2. This mode allows using the USART as an SPI master.

3.18.3 Low-power universal asynchronous receiver transmitter (LPUART)

The devices embed one Low-power UART. The LPUART supports asynchronous serial communication with minimum power consumption. It supports half duplex single wire communication and modem operations (CTS/RTS). It allows multiprocessor communication.

The LPUART has a clock domain independent from the CPU clock. It can wake up the system from Stop mode using baudrates up to 46 Kbaud. The Wakeup events from Stop mode are programmable and can be:

- Start bit detection
- Or any received data frame
- Or a specific programmed data frame

3.19 Clock recovery system (CRS)

The STM32L082xx embeds a special block which allows automatic trimming of the internal 48 MHz oscillator to guarantee its optimal accuracy over the whole device operational range. This automatic trimming is based on the external synchronization signal, which could be either derived from USB SOF signalization, from LSE oscillator, from an external signal on CRS_SYNC pin or generated by user software. For faster lock-in during startup it is also possible to combine automatic trimming with manual trimming action.

3.20 Cyclic redundancy check (CRC) calculation unit

The CRC (cyclic redundancy check) calculation unit is used to get a CRC code using a configurable generator polynomial value and size.

Among other applications, CRC-based techniques are used to verify data transmission or storage integrity. In the scope of the EN/IEC 60335-1 standard, they offer a means of verifying the Flash memory integrity. The CRC calculation unit helps compute a signature of the software during runtime, to be compared with a reference signature generated at linktime and stored at a given memory location.

3.21 Serial wire debug port (SW-DP)

An ARM SW-DP interface is provided to allow a serial wire debugging tool to be connected to the MCU.

2. V_{DD_USB} must respect the following conditions:
 - When V_{DD} is powered on ($V_{DD} < V_{DD_min}$), V_{DD_USB} should be always lower than V_{DD} .
 - When V_{DD} is powered down ($V_{DD} < V_{DD_min}$), V_{DD_USB} should be always lower than V_{DD} .
 - In operating mode, V_{DD_USB} could be lower or higher V_{DD} .
 - If the USB is not used, V_{DD_USB} must range from V_{DD_min} to V_{DD_max} to be able to use PA11 and PA12 as standard I/Os.
3. To sustain a voltage higher than $V_{DD}+0.3V$, the internal pull-up/pull-down resistors must be disabled.
4. If T_A is lower, higher P_D values are allowed as long as T_J does not exceed T_J max (see [Table 82: Thermal characteristics on page 115](#)).

Table 26. Embedded internal reference voltage⁽¹⁾ (continued)

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|--------------------------|---|------------|-----|-----|------|-------------------|
| $I_{LPBUF}^{(4)}$ | Consumption of reference voltage buffer for VREF_OUT and COMP | - | - | 730 | 1200 | nA |
| $V_{REFINT_DIV1}^{(4)}$ | 1/4 reference voltage | - | 24 | 25 | 26 | % V_{REFINT} |
| $V_{REFINT_DIV2}^{(4)}$ | 1/2 reference voltage | - | 49 | 50 | 51 | |
| $V_{REFINT_DIV3}^{(4)}$ | 3/4 reference voltage | - | 74 | 75 | 76 | |

1. Refer to [Table 38: Peripheral current consumption in Stop and Standby mode](#) for the value of the internal reference current consumption (I_{REFINT}).
2. Guaranteed by test in production.
3. The internal V_{REF} value is individually measured in production and stored in dedicated EEPROM bytes.
4. Guaranteed by design.
5. Shortest sampling time can be determined in the application by multiple iterations.
6. To guarantee less than 1% VREF_OUT deviation.

6.3.4 Supply current characteristics

The current consumption is a function of several parameters and factors such as the operating voltage, temperature, I/O pin loading, device software configuration, operating frequencies, I/O pin switching rate, program location in memory and executed binary code. The current consumption is measured as described in [Figure 10: Current consumption measurement scheme](#).

All Run-mode current consumption measurements given in this section are performed with a reduced code that gives a consumption equivalent to Dhrystone 2.1 code if not specified otherwise.

The current consumption values are derived from the tests performed under ambient temperature and V_{DD} supply voltage conditions summarized in [Table 23: General operating conditions](#) unless otherwise specified.

The MCU is placed under the following conditions:

- All I/O pins are configured in analog input mode
- All peripherals are disabled except when explicitly mentioned
- The Flash memory access time and prefetch is adjusted depending on fHCLK frequency and voltage range to provide the best CPU performance unless otherwise specified.
- When the peripherals are enabled $f_{APB1} = f_{APB2} = f_{APB}$
- When PLL is on, the PLL inputs are equal to HSI = 16 MHz (if internal clock is used) or HSE = 16 MHz (if HSE bypass mode is used)
- The HSE user clock applied to OSCI_IN input follows the characteristic specified in [Table 40: High-speed external user clock characteristics](#)
- For maximum current consumption $V_{DD} = V_{DDA} = 3.6$ V is applied to all supply pins
- For typical current consumption $V_{DD} = V_{DDA} = 3.0$ V is applied to all supply pins if not specified otherwise

The parameters given in [Table 48](#), [Table 23](#) and [Table 24](#) are derived from tests performed under ambient temperature and V_{DD} supply voltage conditions summarized in [Table 23](#).

Table 27. Current consumption in Run mode, code with data processing running from Flash memory

| Symbol | Parameter | Condition | | f _{HCLK} (MHz) | Typ | Max ⁽¹⁾ | Unit |
|---|--|--|---------------------------------------|----------------------------|------|--------------------|------|
| I _{DD} (Run from Flash memory) | Supply current in Run mode code executed from Flash memory | f _{HSE} = f _{HCLK} up to 16MHz included, f _{HSE} = f _{HCLK} /2 above 16 MHz (PLL ON) ⁽²⁾ | Range3, Vcore=1.2 V VOS[1:0]=11 | 1 | 190 | 250 | μA |
| | | | | 2 | 345 | 380 | |
| | | | | 4 | 650 | 670 | |
| | | | Range2, Vcore=1.5 V VOS[1:0]=10 | 4 | 0,8 | 0,86 | mA |
| | | | | 8 | 1,55 | 1,7 | |
| | | | | 16 | 2,95 | 3,1 | |
| | | | Range1, Vcore=1.8 V VOS[1:0]=01 | 8 | 1,9 | 2,1 | |
| | | | | 16 | 3,55 | 3,8 | |
| | | | | 32 | 6,65 | 7,2 | |
| | | MSI clock source | Range3, Vcore=1.2 V VOS[1:0]=11 | 0,065 | 39 | 130 | μA |
| | | | | 0,524 | 115 | 210 | |
| | | | | 4,2 | 700 | 770 | |
| | | HSI clock source (16MHz) | Range2, Vcore=1.5 V VOS[1:0]=10 | 16 | 2,9 | 3,2 | mA |
| | | | Range1, Vcore=1.8 V VOS[1:0]=01 | 32 | 7,15 | 7,4 | |

1. Guaranteed by characterization results at 125 °C, unless otherwise specified.

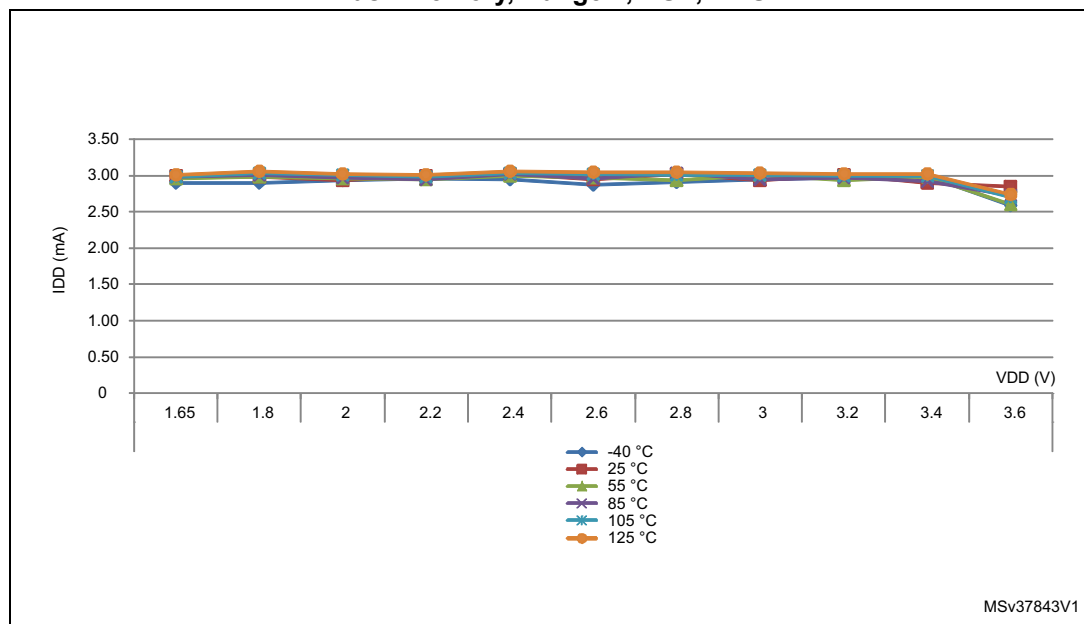
2. Oscillator bypassed (HSEBYP = 1 in RCC_CR register).

Table 28. Current consumption in Run mode vs code type, code with data processing running from Flash memory

| Symbol | Parameter | Conditions | | | f _{HCLK} | Typ | Unit |
|--|---|--|--|-----------------------------|-------------------|------|------|
| I _{DD} (Run from Flash memory) | Supply current in Run mode, code executed from Flash memory | f _{HSE} = f _{HCLK} up to 16 MHz included, f _{HSE} = f _{HCLK} /2 above 16 MHz (PLL on) ⁽¹⁾ | Range 3, V _{CORE} =1.2 V, VOS[1:0]=11 | Dhrystone | 4 MHz | 650 | μA |
| | | | | CoreMark | | 655 | |
| | | | | Fibonacci | | 485 | |
| | | | | while(1) | | 385 | |
| | | | | while(1), 1WS, prefetch off | | 375 | |
| | | | Range 1, V _{CORE} =1.8 V, VOS[1:0]=01 | Dhrystone | 32 MHz | 6,65 | mA |
| | | | | CoreMark | | 6,9 | |
| | | | | Fibonacci | | 6,75 | |
| | | | | while(1) | | 5,8 | |
| | | | | while(1), prefetch off | | 5,5 | |

1. Oscillator bypassed (HSEBYP = 1 in RCC_CR register).

Figure 11. I_{DD} vs V_{DD}, at T_A= 25/55/85/105 °C, Run mode, code running from Flash memory, Range 2, HSE, 1WS



2. Oscillator bypassed (HSEBYP = 1 in RCC_CR register).

**Table 30. Current consumption in Run mode vs code type,
code with data processing running from RAM⁽¹⁾**

| Symbol | Parameter | Conditions | | | f _{HCLK} | Typ | Unit |
|--------------------------------|---|---|--|-----------|-------------------|------|------|
| I _{DD} (Run from RAM) | Supply current in Run mode, code executed from RAM, Flash memory switched off | f _{HSE} = f _{HCLK} up to 16 MHz included, f _{HSE} = f _{HCLK} /2 above 16 MHz (PLL on) ⁽²⁾ | Range 3, V _{CORE} =1.2 V, VOS[1:0]=11 | Dhrystone | 4 MHz | 570 | μA |
| | | | | CoreMark | | 670 | |
| | | | | Fibonacci | | 410 | |
| | | | | while(1) | | 375 | |
| | | Range 1, V _{CORE} =1.8 V, VOS[1:0]=01 | | Dhrystone | 32 MHz | 6,65 | mA |
| | | | | CoreMark | | 6,95 | |
| | | | | Fibonacci | | 5,9 | |
| | | | | while(1) | | 5,2 | |

1. Guaranteed by characterization results, unless otherwise specified.

2. Oscillator bypassed (HSEBYP = 1 in RCC_CR register).

Table 39. Low-power mode wakeup timings (continued)

| Symbol | Parameter | Conditions | Typ | Max | Unit |
|---------------|---|---|-----|-----|---------------|
| t_{WUSTOP} | Wakeup from Stop mode, regulator in Run mode | $f_{HCLK} = f_{MSI} = 4.2 \text{ MHz}$ | 5.0 | 8 | μs |
| | | $f_{HCLK} = f_{HSI} = 16 \text{ MHz}$ | 4.9 | 7 | |
| | | $f_{HCLK} = f_{HSI}/4 = 4 \text{ MHz}$ | 8.0 | 11 | |
| | Wakeup from Stop mode, regulator in low-power mode | $f_{HCLK} = f_{MSI} = 4.2 \text{ MHz}$ Voltage range 1 | 5.0 | 8 | |
| | | $f_{HCLK} = f_{MSI} = 4.2 \text{ MHz}$ Voltage range 2 | 5.0 | 8 | |
| | | $f_{HCLK} = f_{MSI} = 4.2 \text{ MHz}$ Voltage range 3 | 5.0 | 8 | |
| | | $f_{HCLK} = f_{MSI} = 2.1 \text{ MHz}$ | 7.3 | 13 | |
| | | $f_{HCLK} = f_{MSI} = 1.05 \text{ MHz}$ | 13 | 23 | |
| | | $f_{HCLK} = f_{MSI} = 524 \text{ kHz}$ | 28 | 38 | |
| | | $f_{HCLK} = f_{MSI} = 262 \text{ kHz}$ | 51 | 65 | |
| | | $f_{HCLK} = f_{MSI} = 131 \text{ kHz}$ | 100 | 120 | |
| | | $f_{HCLK} = f_{MSI} = 65 \text{ kHz}$ | 190 | 260 | |
| | | $f_{HCLK} = f_{HSI} = 16 \text{ MHz}$ | 4.9 | 7 | |
| | | $f_{HCLK} = f_{HSI}/4 = 4 \text{ MHz}$ | 8.0 | 11 | |
| | Wakeup from Stop mode, regulator in low-power mode, code running from RAM | $f_{HCLK} = f_{HSI} = 16 \text{ MHz}$ | 4.9 | 7 | |
| | | $f_{HCLK} = f_{HSI}/4 = 4 \text{ MHz}$ | 7.9 | 10 | |
| | | $f_{HCLK} = f_{MSI} = 4.2 \text{ MHz}$ | 4.7 | 8 | |
| $t_{WUSTDBY}$ | Wakeup from Standby mode FWU bit = 1 | $f_{HCLK} = f_{MSI} = 2.1 \text{ MHz}$ | 65 | 130 | ms |
| | Wakeup from Standby mode FWU bit = 0 | $f_{HCLK} = f_{MSI} = 2.1 \text{ MHz}$ | 2.2 | 3 | |

Low-speed external user clock generated from an external source

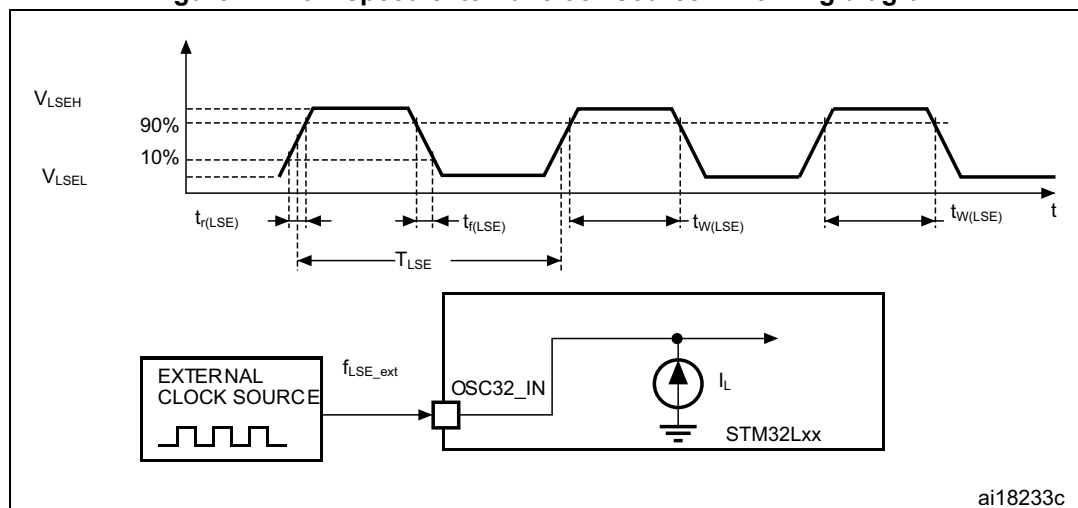
The characteristics given in the following table result from tests performed using a low-speed external clock source, and under ambient temperature and supply voltage conditions summarized in [Table 23](#).

Table 41. Low-speed external user clock characteristics⁽¹⁾

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|------------------------------|---------------------------------------|----------------------------------|-------------|--------|-------------|---------|
| f_{LSE_ext} | User external clock source frequency | - | 1 | 32.768 | 1000 | kHz |
| V_{LSEH} | OSC32_IN input pin high level voltage | | $0.7V_{DD}$ | - | V_{DD} | V |
| V_{LSEL} | OSC32_IN input pin low level voltage | | V_{SS} | - | $0.3V_{DD}$ | |
| $t_{w(LSE)}$ $t_{w(LSE)}$ | OSC32_IN high or low time | | 465 | - | - | ns |
| $t_{r(LSE)}$ $t_{f(LSE)}$ | OSC32_IN rise or fall time | | - | - | 10 | |
| $C_{IN(LSE)}$ | OSC32_IN input capacitance | - | - | 0.6 | - | pF |
| $DuCy_{(LSE)}$ | Duty cycle | - | 45 | - | 55 | % |
| I_L | OSC32_IN Input leakage current | $V_{SS} \leq V_{IN} \leq V_{DD}$ | - | - | ± 1 | μA |

1. Guaranteed by design, not tested in production

Figure 17. Low-speed external clock source AC timing diagram



6.3.13 I/O port characteristics

General input/output characteristics

Unless otherwise specified, the parameters given in [Table 57](#) are derived from tests performed under the conditions summarized in [Table 23](#). All I/Os are CMOS and TTL compliant.

Table 57. I/O static characteristics

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-----------|---|--|--------------|---------------------|--------------------|------------|
| V_{IL} | Input low level voltage | TC, FT, FTf, RST I/Os | - | - | $0.3V_{DD}$ | V |
| | | BOOT0 pin | - | - | $0.14V_{DD}^{(1)}$ | |
| V_{IH} | Input high level voltage | All I/Os | $0.7 V_{DD}$ | - | - | |
| V_{hys} | I/O Schmitt trigger voltage hysteresis ⁽²⁾ | Standard I/Os | - | $10\% V_{DD}^{(3)}$ | - | |
| | | BOOT0 pin | - | 0.01 | - | |
| I_{lkg} | Input leakage current ⁽⁴⁾ | $V_{SS} \leq V_{IN} \leq V_{DD}$ All I/Os except for PA11, PA12, BOOT0 and FTf I/Os | - | - | ± 50 | nA |
| | | $V_{SS} \leq V_{IN} \leq V_{DD}$, PA11 and PA12 I/Os | - | - | -50/+250 | |
| | | $V_{SS} \leq V_{IN} \leq V_{DD}$ FTf I/Os | - | - | ± 100 | |
| | | $V_{DD} \leq V_{IN} \leq 5 V$ All I/Os except for PA11, PA12, BOOT0 and FTf I/Os | - | - | 200 | nA |
| | | $V_{DD} \leq V_{IN} \leq 5 V$ FTf I/Os | - | - | 500 | |
| | | $V_{DD} \leq V_{IN} \leq 5 V$ PA11, PA12 and BOOT0 | - | - | 10 | μA |
| R_{PU} | Weak pull-up equivalent resistor ⁽⁵⁾ | $V_{IN} = V_{SS}$ | 30 | 45 | 60 | k Ω |
| R_{PD} | Weak pull-down equivalent resistor ⁽⁵⁾ | $V_{IN} = V_{DD}$ | 30 | 45 | 60 | k Ω |
| C_{IO} | I/O pin capacitance | - | - | 5 | - | pF |

1. Guaranteed by characterization.

2. Hysteresis voltage between Schmitt trigger switching levels. Guaranteed by characterization results.

3. With a minimum of 200 mV. Guaranteed by characterization results.

4. The max. value may be exceeded if negative current is injected on adjacent pins.

5. Pull-up and pull-down resistors are designed with a true resistance in series with a switchable PMOS/NMOS. This MOS/NMOS contribution to the series resistance is minimum (~10% order).

Output voltage levels

Unless otherwise specified, the parameters given in [Table 58](#) are derived from tests performed under ambient temperature and V_{DD} supply voltage conditions summarized in [Table 23](#). All I/Os are CMOS and TTL compliant.

Table 58. Output voltage characteristics

| Symbol | Parameter | Conditions | Min | Max | Unit |
|----------------------|---|--|---------------|------|------|
| $V_{OL}^{(1)}$ | Output low level voltage for an I/O pin | CMOS port ⁽²⁾ , $I_{IO} = +8 \text{ mA}$ $2.7 \text{ V} \leq V_{DD} \leq 3.6 \text{ V}$ | - | 0.4 | V |
| $V_{OH}^{(3)}$ | Output high level voltage for an I/O pin | | $V_{DD}-0.4$ | - | |
| $V_{OL}^{(1)}$ | Output low level voltage for an I/O pin | TTL port ⁽²⁾ , $I_{IO} = +8 \text{ mA}$ $2.7 \text{ V} \leq V_{DD} \leq 3.6 \text{ V}$ | - | 0.4 | |
| $V_{OH}^{(3)(4)}$ | Output high level voltage for an I/O pin | TTL port ⁽²⁾ , $I_{IO} = -6 \text{ mA}$ $2.7 \text{ V} \leq V_{DD} \leq 3.6 \text{ V}$ | 2.4 | - | |
| $V_{OL}^{(1)(4)}$ | Output low level voltage for an I/O pin | $I_{IO} = +15 \text{ mA}$ $2.7 \text{ V} \leq V_{DD} \leq 3.6 \text{ V}$ | - | 1.3 | |
| $V_{OH}^{(3)(4)}$ | Output high level voltage for an I/O pin | $I_{IO} = -15 \text{ mA}$ $2.7 \text{ V} \leq V_{DD} \leq 3.6 \text{ V}$ | $V_{DD}-1.3$ | - | |
| $V_{OL}^{(1)(4)}$ | Output low level voltage for an I/O pin | $I_{IO} = +4 \text{ mA}$ $1.65 \text{ V} \leq V_{DD} < 3.6 \text{ V}$ | - | 0.45 | |
| $V_{OH}^{(3)(4)}$ | Output high level voltage for an I/O pin | $I_{IO} = -4 \text{ mA}$ $1.65 \text{ V} \leq V_{DD} \leq 3.6 \text{ V}$ | $V_{DD}-0.45$ | - | |
| $V_{OLFM+}^{(1)(4)}$ | Output low level voltage for an FTf I/O pin in Fm+ mode | $I_{IO} = 20 \text{ mA}$ $2.7 \text{ V} \leq V_{DD} \leq 3.6 \text{ V}$ | - | 0.4 | |
| | | $I_{IO} = 10 \text{ mA}$ $1.65 \text{ V} \leq V_{DD} \leq 3.6 \text{ V}$ | - | 0.4 | |

1. The I_{IO} current sunk by the device must always respect the absolute maximum rating specified in [Table 21](#). The sum of the currents sunk by all the I/Os (I/O ports and control pins) must always be respected and must not exceed $\Sigma I_{IO(PIN)}$.
2. TTL and CMOS outputs are compatible with JEDEC standards JESD36 and JESD52.
3. The I_{IO} current sourced by the device must always respect the absolute maximum rating specified in [Table 21](#). The sum of the currents sourced by all the I/Os (I/O ports and control pins) must always be respected and must not exceed $\Sigma I_{IO(PIN)}$.
4. Guaranteed by characterization results.

Input/output AC characteristics

The definition and values of input/output AC characteristics are given in [Figure 23](#) and [Table 59](#), respectively.

Unless otherwise specified, the parameters given in [Table 59](#) are derived from tests performed under ambient temperature and V_{DD} supply voltage conditions summarized in [Table 23](#).

Table 59. I/O AC characteristics⁽¹⁾

| OSPEEDRx[1:0] bit value ⁽¹⁾ | Symbol | Parameter | Conditions | Min | Max ⁽²⁾ | Unit |
|---|--|---|---|-----|--------------------|------|
| 00 | $f_{\max(\text{IO})\text{out}}$ | Maximum frequency ⁽³⁾ | $C_L = 50 \text{ pF}$, $V_{DD} = 2.7 \text{ V to } 3.6 \text{ V}$ | - | 400 | kHz |
| | | | $C_L = 50 \text{ pF}$, $V_{DD} = 1.65 \text{ V to } 2.7 \text{ V}$ | - | 100 | |
| | $t_{f(\text{IO})\text{out}}$ $t_{r(\text{IO})\text{out}}$ | Output rise and fall time | $C_L = 50 \text{ pF}$, $V_{DD} = 2.7 \text{ V to } 3.6 \text{ V}$ | - | 125 | ns |
| | | | $C_L = 50 \text{ pF}$, $V_{DD} = 1.65 \text{ V to } 2.7 \text{ V}$ | - | 320 | |
| 01 | $f_{\max(\text{IO})\text{out}}$ | Maximum frequency ⁽³⁾ | $C_L = 50 \text{ pF}$, $V_{DD} = 2.7 \text{ V to } 3.6 \text{ V}$ | - | 2 | MHz |
| | | | $C_L = 50 \text{ pF}$, $V_{DD} = 1.65 \text{ V to } 2.7 \text{ V}$ | - | 0.6 | |
| | $t_{f(\text{IO})\text{out}}$ $t_{r(\text{IO})\text{out}}$ | Output rise and fall time | $C_L = 50 \text{ pF}$, $V_{DD} = 2.7 \text{ V to } 3.6 \text{ V}$ | - | 30 | ns |
| | | | $C_L = 50 \text{ pF}$, $V_{DD} = 1.65 \text{ V to } 2.7 \text{ V}$ | - | 65 | |
| 10 | $F_{\max(\text{IO})\text{out}}$ | Maximum frequency ⁽³⁾ | $C_L = 50 \text{ pF}$, $V_{DD} = 2.7 \text{ V to } 3.6 \text{ V}$ | - | 10 | MHz |
| | | | $C_L = 50 \text{ pF}$, $V_{DD} = 1.65 \text{ V to } 2.7 \text{ V}$ | - | 2 | |
| | $t_{f(\text{IO})\text{out}}$ $t_{r(\text{IO})\text{out}}$ | Output rise and fall time | $C_L = 50 \text{ pF}$, $V_{DD} = 2.7 \text{ V to } 3.6 \text{ V}$ | - | 13 | ns |
| | | | $C_L = 50 \text{ pF}$, $V_{DD} = 1.65 \text{ V to } 2.7 \text{ V}$ | - | 28 | |
| 11 | $F_{\max(\text{IO})\text{out}}$ | Maximum frequency ⁽³⁾ | $C_L = 30 \text{ pF}$, $V_{DD} = 2.7 \text{ V to } 3.6 \text{ V}$ | - | 35 | MHz |
| | | | $C_L = 50 \text{ pF}$, $V_{DD} = 1.65 \text{ V to } 2.7 \text{ V}$ | - | 10 | |
| | $t_{f(\text{IO})\text{out}}$ $t_{r(\text{IO})\text{out}}$ | Output rise and fall time | $C_L = 30 \text{ pF}$, $V_{DD} = 2.7 \text{ V to } 3.6 \text{ V}$ | - | 6 | ns |
| | | | $C_L = 50 \text{ pF}$, $V_{DD} = 1.65 \text{ V to } 2.7 \text{ V}$ | - | 17 | |
| Fm+ configuration ⁽⁴⁾ | $f_{\max(\text{IO})\text{out}}$ | Maximum frequency ⁽³⁾ | $C_L = 50 \text{ pF}$, $V_{DD} = 2.5 \text{ V to } 3.6 \text{ V}$ | - | 1 | MHz |
| | $t_{f(\text{IO})\text{out}}$ | Output fall time | | - | 10 | ns |
| | $t_{r(\text{IO})\text{out}}$ | Output rise time | | - | 30 | |
| | $f_{\max(\text{IO})\text{out}}$ | Maximum frequency ⁽³⁾ | $C_L = 50 \text{ pF}$, $V_{DD} = 1.65 \text{ V to } 3.6 \text{ V}$ | - | 350 | KHz |
| | $t_{f(\text{IO})\text{out}}$ | Output fall time | | - | 15 | ns |
| | $t_{r(\text{IO})\text{out}}$ | Output rise time | | - | 60 | |
| - | $t_{\text{EXTI}pw}$ | Pulse width of external signals detected by the EXTI controller | - | 8 | - | ns |

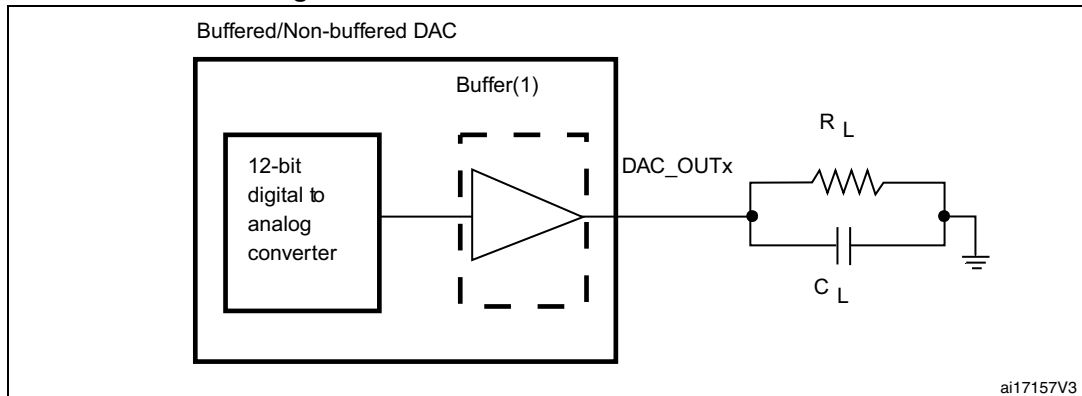
1. The I/O speed is configured using the OSPEEDRx[1:0] bits. Refer to the line reference manual for a description of GPIO Port configuration register.
2. Guaranteed by design.
3. The maximum frequency is defined in [Figure 23](#).
4. When Fm+ configuration is set, the I/O speed control is bypassed. Refer to the line reference manual for a detailed description of Fm+ I/O configuration.

Table 61. ADC characteristics (continued)

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|------------------------|---|--|--|-----|--------------------------------------|------------------|
| $C_{ADC}^{(3)}$ | Internal sample and hold capacitor | - | - | - | 8 | pF |
| $t_{CAL}^{(3)(5)}$ | Calibration time | $f_{ADC} = 16 \text{ MHz}$ | 5.2 | | | μs |
| | | - | 83 | | | $1/f_{ADC}$ |
| $W_{LATENCY}^{(6)}$ | ADC_DR register write latency | ADC clock = HSI16 | 1.5 ADC cycles + 2 f_{PCLK} cycles | - | 1.5 ADC cycles + 3 f_{PCLK} cycles | - |
| | | ADC clock = PCLK/2 | - | 4.5 | - | f_{PCLK} cycle |
| | | ADC clock = PCLK/4 | - | 8.5 | - | f_{PCLK} cycle |
| $t_{latr}^{(3)}$ | Trigger conversion latency | $f_{ADC} = f_{PCLK}/2 = 16 \text{ MHz}$ | 0.266 | | | μs |
| | | $f_{ADC} = f_{PCLK}/2$ | 8.5 | | | $1/f_{PCLK}$ |
| | | $f_{ADC} = f_{PCLK}/4 = 8 \text{ MHz}$ | 0.516 | | | μs |
| | | $f_{ADC} = f_{PCLK}/4$ | 16.5 | | | $1/f_{PCLK}$ |
| | | $f_{ADC} = f_{HSI16} = 16 \text{ MHz}$ | 0.252 | - | 0.260 | μs |
| Jitter _{ADC} | ADC jitter on trigger conversion | $f_{ADC} = f_{HSI16}$ | - | 1 | - | $1/f_{HSI16}$ |
| $t_S^{(3)}$ | Sampling time | $f_{ADC} = 16 \text{ MHz}$ | 0.093 | - | 10.03 | μs |
| | | - | 1.5 | - | 160.5 | $1/f_{ADC}$ |
| $t_{UP_LDO}^{(3)(5)}$ | Internal LDO power-up time | - | - | - | 10 | μs |
| $t_{STAB}^{(3)(5)}$ | ADC stabilization time | - | 14 | | | $1/f_{ADC}$ |
| $t_{ConV}^{(3)}$ | Total conversion time (including sampling time) | $f_{ADC} = 16 \text{ MHz}$, 12-bit resolution | 0.875 | - | 10.81 | μs |
| | | 12-bit resolution | 14 to 173 (t_S for sampling +12.5 for successive approximation) | | | $1/f_{ADC}$ |

1. V_{DDA} minimum value can be decreased in specific temperature conditions. Refer to [Table 62: RAIN max for \$f_{ADC} = 16 \text{ MHz}\$](#) .
2. A current consumption proportional to the APB clock frequency has to be added (see [Table 37: Peripheral current consumption in Run or Sleep mode](#)).
3. Guaranteed by design.
4. Standard channels have an extra protection resistance which depends on supply voltage. Refer to [Table 62: RAIN max for \$f_{ADC} = 16 \text{ MHz}\$](#) .
5. This parameter only includes the ADC timing. It does not take into account register access latency.
6. This parameter specifies the latency to transfer the conversion result into the ADC_DR register. EOC bit is set to indicate the conversion is complete and has the same latency.

6. Difference between the value measured at Code (0x800) and the ideal value = $V_{REF+}/2$.
7. Difference between the value measured at Code (0x001) and the ideal value.
8. Difference between ideal slope of the transfer function and measured slope computed from code 0x000 and 0xFF when buffer is off, and from code giving 0.2 V and ($V_{DDA} - 0.2$) V when buffer is on.
9. In buffered mode, the output can overshoot above the final value for low input code (starting from min value).

Figure 29. 12-bit buffered/non-buffered DAC

6.3.17 Temperature sensor characteristics

Table 65. Temperature sensor calibration values

| Calibration value name | Description | Memory address |
|------------------------|--|---------------------------|
| TS_CAL1 | TS ADC raw data acquired at temperature of 30 °C, $V_{DDA} = 3$ V | 0x1FF8 007A - 0x1FF8 007B |
| TS_CAL2 | TS ADC raw data acquired at temperature of 130 °C, $V_{DDA} = 3$ V | 0x1FF8 007E - 0x1FF8 007F |

Table 66. Temperature sensor characteristics

| Symbol | Parameter | Min | Typ | Max | Unit |
|--------------------------|--|------|---------|---------|-------|
| $T_L^{(1)}$ | V_{SENSE} linearity with temperature | - | ± 1 | ± 2 | °C |
| Avg_Slope ⁽¹⁾ | Average slope | 1.48 | 1.61 | 1.75 | mV/°C |
| V_{130} | Voltage at 130°C $\pm 5^\circ\text{C}^{(2)}$ | 640 | 670 | 700 | mV |
| $I_{DDA(TEMP)}^{(3)}$ | Current consumption | - | 3.4 | 6 | μA |
| $t_{START}^{(3)}$ | Startup time | - | - | 10 | μs |
| $T_{S_temp}^{(4)(3)}$ | ADC sampling time when reading the temperature | 10 | - | - | |

1. Guaranteed by characterization results.

2. Measured at $V_{DD} = 3$ V ± 10 mV. V_{130} ADC conversion result is stored in the TS_CAL2 byte.

3. Guaranteed by design.

4. Shortest sampling time can be determined in the application by multiple iterations.

Table 73. SPI characteristics in voltage Range 2 ⁽¹⁾

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|--------------------------------|-----------------------------------|--|--------------------|------------|------------------|------|
| f_{SCK} $1/t_{c(SCK)}$ | SPI clock frequency | Master mode | - | - | 8 | MHz |
| | | Slave mode Transmitter $1.65 < V_{DD} < 3.6V$ | | | 8 | |
| | | Slave mode Transmitter $2.7 < V_{DD} < 3.6V$ | | | 8 ⁽²⁾ | |
| $Duty_{(SCK)}$ | Duty cycle of SPI clock frequency | Slave mode | 30 | 50 | 70 | % |
| $t_{su(NSS)}$ | NSS setup time | Slave mode, SPI presc = 2 | $4 \cdot T_{pclk}$ | - | - | ns |
| $t_{h(NSS)}$ | NSS hold time | Slave mode, SPI presc = 2 | $2 \cdot T_{pclk}$ | - | - | |
| $t_{w(SCKH)}$ $t_{w(SCKL)}$ | SCK high and low time | Master mode | $T_{pclk} - 2$ | T_{pclk} | $T_{pclk} + 2$ | |
| $t_{su(MI)}$ | Data input setup time | Master mode | 0 | - | - | |
| $t_{su(SI)}$ | | Slave mode | 3 | - | - | |
| $t_{h(MI)}$ | Data input hold time | Master mode | 11 | - | - | |
| $t_{h(SI)}$ | | Slave mode | 4.5 | - | - | |
| $t_{a(SO)}$ | Data output access time | Slave mode | 18 | - | 52 | |
| $t_{dis(SO)}$ | Data output disable time | Slave mode | 12 | - | 42 | |
| $t_{v(SO)}$ | Data output valid time | Slave mode | - | 20 | 56.5 | |
| $t_{v(MO)}$ | | Master mode | - | 5 | 9 | |
| $t_{h(SO)}$ | Data output hold time | Slave mode | 13 | - | - | |
| $t_{h(MO)}$ | | Master mode | 3 | - | - | |

1. Guaranteed by characterization results.

2. The maximum SPI clock frequency in slave transmitter mode is determined by the sum of $t_{v(SO)}$ and $t_{su(MI)}$ which has to fit into SCK low or high phase preceding the SCK sampling edge. This value can be achieved when the SPI communicates with a master having $t_{su(MI)} = 0$ while $Duty_{(SCK)} = 50\%$.

USB characteristics

The USB interface is USB-IF certified (full speed).

Table 75. USB startup time

| Symbol | Parameter | Max | Unit |
|----------------------------|------------------------------|-----|---------------|
| $t_{\text{STARTUP}}^{(1)}$ | USB transceiver startup time | 1 | μs |

1. Guaranteed by design.

Table 76. USB DC electrical characteristics

| Symbol | Parameter | Conditions | Min. ⁽¹⁾ | Max. ⁽¹⁾ | Unit |
|--------------------------------|---------------------------------|---|---------------------|---------------------|------|
| Input levels | | | | | |
| V _{DD} | USB operating voltage | - | 3.0 | 3.6 | V |
| V _{DI} ⁽²⁾ | Differential input sensitivity | I(USB_DP, USB_DM) | 0.2 | - | V |
| V _{CM} ⁽²⁾ | Differential common mode range | Includes V _{DI} range | 0.8 | 2.5 | |
| V _{SE} ⁽²⁾ | Single ended receiver threshold | - | 1.3 | 2.0 | |
| Output levels | | | | | |
| V _{OL} ⁽³⁾ | Static output level low | R _L of 1.5 kΩ to 3.6 V ⁽⁴⁾ | - | 0.3 | V |
| V _{OH} ⁽³⁾ | Static output level high | R _L of 15 kΩ to V _{SS} ⁽⁴⁾ | 2.8 | 3.6 | |

1. All the voltages are measured from the local ground potential.
2. Guaranteed by characterization results.
3. Guaranteed by test in production.
4. R_{L} is the load connected on the USB drivers.